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multicomp		DCP #	REV	DESCRIPTION			DATE	СНЕСКД	DATE	APPRV	DATE	
mancomp	TECHNOLOGT.	1447	A	RELEASED			5/19/04	SF	8/10/04	JC	8/10/04	
	SPC-F005.DWG	1885	В	UPDATED TO ROHS CO	MPLIANCE	E EO	02/03/06	но	2/6/06	но	2/6/06	
	TO-220 NPN Silicon Power Transistor. Ney are particularly suited for 115-220				gned fo	r high vo	ltage, ł	nigh s	peed, F	'ower		
Features: - Switching regulators - DC-DC convertors - Inverters - Solenoid and relay drivers - Motor controls			1. E 2. (3. E 4. (Configuration: Base Collector Emitter Collector	(_			ξ	E C	RoHS Compli		
Absolute Maximum Ratings: - Collector-Emitter Voltage, V _{CEV}	= 700V 2	,		al Characteristics:				other	wise s			
– Collector-Emitter Voltage, V _{CEO}	= 400V	l	Parameter		Symbol	Test Condition	15			Min	Max Unit	
- Emitter-Base Voltage, V _{EBO} =	9V	r	OFF Chara		h. I							
 Continuous Collector Current, I_C = 4A Base Current, I_B = 2A 				Emitter Breakdown Voltage		$I_{\rm C} = 10 {\rm mA},$				400	- V	
- Total Device Dissipation ($T_c =$	+25°C), Pp = 75W	-		Cut-Off Current		$V_{CE} = 700V,$		1.5V		-	1 mA	
	te above 25°C = 0.6W/°C	ı		ut-Off Current	I _{EBO}	$V_{\text{EB}} = 9V, I_{\text{C}}$	= 0			-	1 mA	
 Operating Junction Temperatur 	re Range, $T_{J} = -65^{\circ}C$ to $+150^{\circ}C$,	ON Charac	teristics								
− Storage Temperature Range, T _{sta} = −65°C to +150°C			DC Current Gain, Note 1 h _{FE} V _{CE}		$V_{CE} = 5V$, I_C	= 1A			10			
	9					V_{CE} = 5V, I_{C}	= 2A			-	40 –	
			Collector-	Emitter Saturation Voltage	V _{CE(sat)}	\mathbf{I}_{C} = 1A, \mathbf{I}_{B} :	= 200mA			-	0.5 V	
· · · · · · · · ·	C		Note 1			\mathbf{I}_{C} = 2A, \mathbf{I}_{B} =	= 500mA			-	0.6 V	
	- =		Base-Emi	tter Saturation Voltage	V _{BE(sat)}	$I_{\rm C}$ = 1A, $I_{\rm B}$ =	= 200mA				1.2 V	
			Note 1		DE(BUT)	$I_{C} = 2A, I_{B} =$	= 500mA			-	1.6 V	
$ \uparrow \neg \lor $	- 3 Collector	ı	Small-Sign	al Characteristics								
		[Current G	ain-Bandwidth Product	fT	$V_{CE} = 10V, I$	c = 500r	nA, f =	1MHz	4	– MHz	
			Switching Characteristics									
		r	Delay Tim		t.					_	0.1	
		-	Rise Time	-	tr tr	$V_{CC} = 125V,$	$I_{C} = 2A$,	$I_{B1} = I_{f}$	$_{32} = 0.4A$		0.7	
/ ↓ \// \// \/ `	1 Emitter	-	Storage T	me	te					-	4 μs	
	i Emitter	-	Fall Time	inc .	t.	$V_{CC} = 125V,$	$I_{C} = 2A$,	$I_{B1} = I_{f}$	$_{B2} = 0.4A$		0.9	
				Note 1: Pulse test: Pulse width ≦300µs, Duty cycle ≦2%.								
	Dimensions A B C	D E					(,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	0 _2				
		0.90 1.40	0 3.88 2	79 3.43 0.56 14.73 4.07	2.92 31.	.24 7*						
	TOLERANCES: DRAWN BY:		DATE:	DRAWING TITLE:								
		н	5/19/0	4 Trans	sistor, I	Power, Si	licon, 1	0-22	O, NPN			
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